

General Description

The CLC1200 is a low power, general purpose instrumentation amplifier with a gain range of 1 to 10,000. The CLC1200 is offered in 8-lead SOIC or DIP packages and requires only one external gain setting resistor making it smaller and easier to implement than discrete, 3-amp designs.

While consuming only 2.2mA of supply current, the CLC1200 offers a low 6.6nV/Hz input voltage noise and 0.2μVpp noise from 0.1Hz to 10Hz.

The CLC1200 offers a low input offset voltage of ±125μV that only varies 0.1μV/°C over it's operating temperature range of -40°C to +85°C. The CLC1200 also features 50ppm maximum nonlinearity. These features make it well suited for use in data acquisition systems.

FEATURES

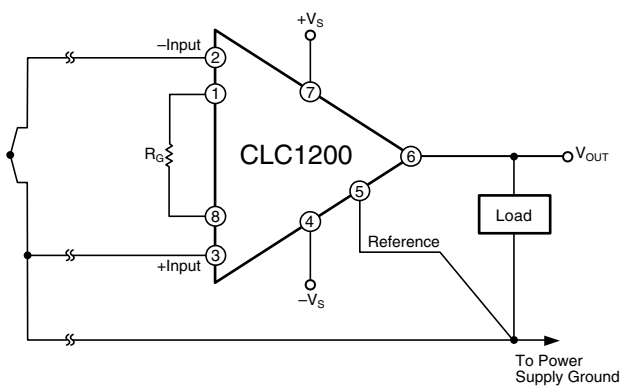
- ±2.3V to ±18V supply voltage range
- Gain range of 1 to 10,000
- Gain set with one external resistor
- ±125μV maximum input offset voltage
- 0.1μV/°C input offset drift
- 700kHz bandwidth at G = 1
- 1.2V/μs slew rate
- 90dB minimum CMRR at G = 10
- 2.2mA maximum supply current
- 6.6nV/√Hz input voltage noise
- 70nV/√Hz output voltage noise
- 0.2μVpp input noise (0.1Hz to 10Hz)
- DIP-8 or Pb-free SOIC-8

APPLICATIONS

- Bridge amplifier
- Weigh scales
- Thermocouple amplifier
- ECG and medical instrumentation
- MRI (Magnetic Resonance Imaging)
- Patient monitors
- Transducer interface
- Data acquisition systems
- Strain gauge amplifier
- Industrial process controls

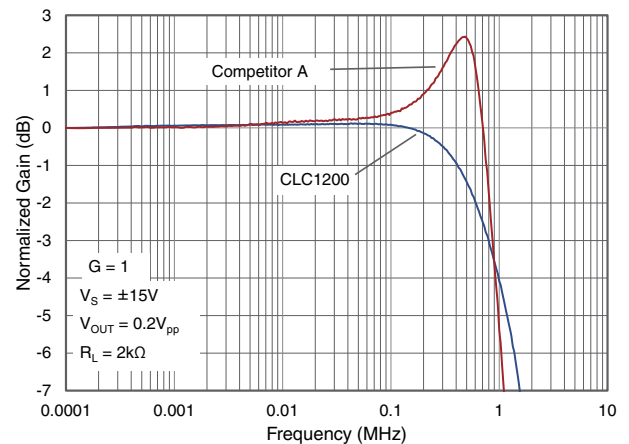
Ordering Information - [back page](#)

Typical Application



Thermocouple Amplifier

Competitive Plot



Absolute Maximum Ratings

Stresses beyond the limits listed below may cause permanent damage to the device. Exposure to any Absolute Maximum Rating condition for extended periods may affect device reliability and lifetime.

Supply Voltage	$\pm 18\text{V}$
Input Voltage Range	$\pm V_S$ V
Differential Input Voltage (G = 1 to 10)	25V
Differential Input Voltage (G > 10)	$\leq 0.05 (R_G + 800) + 1$ V
Load Resistance (min)	1 Ω

Operating Conditions

Supply Voltage Range	$\pm 2.3\text{V}$ to $\pm 18\text{V}$ (4.6V to 36V)
Gain Range	1 to 10,000
Operating Temperature Range	-40°C to 85°C
Junction Temperature	150°C
Storage Temperature Range	-65°C to 150°C
Lead Temperature (Soldering, 10s)	260°C

Package Thermal Resistance

θ_{JA} (DIP-8)	100°C/W
θ_{JA} (SOIC-8)	150°C/W
Package thermal resistance (θ_{JA}), JEDEC standard, multi-layer test boards, still air.	

ESD Protection

SOIC-8 (HBM)	1.5kV
ESD Rating for HBM (Human Body Model).	

Electrical Characteristics

$T_A = 25^\circ\text{C}$, $V_S = \pm 15\text{V}$, $R_L = 2\text{k}\Omega$ to GND; unless otherwise noted. Gain = $1 + (49.4\text{k}/R_G)$; Total RTI Error = $V_{OSI} + (V_{OSO}/G)$

Symbol	Parameter	Conditions	Min	Typ	Max	Units
Gain						
	Gain Range		1		10,000	
	Gain Error ⁽¹⁾	$G = 1, V_{OUT} = \pm 10\text{V}$	-0.1		0.1	%
		$G = 10, V_{OUT} = \pm 10\text{V}$	-0.375		0.375	%
		$G = 100, V_{OUT} = \pm 10\text{V}$	-0.375		0.375	%
		$G = 1,000, V_{OUT} = \pm 10\text{V}$	-0.8		0.8	%
	Gain Nonlinearity	$G = 1 - 100, V_{OUT} = -10\text{V to } 10\text{V}, R_L = 10\text{k}\Omega$		10	50	ppm
		$G = 1 - 100, V_{OUT} = -10\text{V to } 10\text{V}, R_L = 2\text{k}\Omega$		10	95	ppm
	Gain vs. Temperature	$G = 1$		<10		ppm/ $^\circ\text{C}$
		$G > 1$		<-50		ppm/ $^\circ\text{C}$
	Reference Gain Error ⁽¹⁾	$V_S = \pm 16.5\text{V}$	-0.03		0.03	%
Voltage Offset						
V_{OSI}	Input Offset Voltage	$V_S = \pm 4.5\text{V to } \pm 16.5\text{V}$	-125		125	μV
	Average Temperature Coefficient	$V_S = \pm 4.5\text{V to } \pm 16.5\text{V}$		0.1		$\mu\text{V}/^\circ\text{C}$
V_{OSO}	Output Offset Voltage	$V_S = \pm 4.5\text{V to } \pm 16.5\text{V}, G = 1$	-1500	200	1500	μV
	Average Temperature Coefficient	$V_S = \pm 4.5\text{V to } \pm 16.5\text{V}$		2.5		$\mu\text{V}/^\circ\text{C}$
PSR	Offset Referred to the Input vs. Supply	$G = 1, V_S = \pm 2.3\text{V to } \pm 18\text{V}$	80	100		dB
		$G = 10, V_S = \pm 2.3\text{V to } \pm 18\text{V}$	95	120		dB
		$G = 100, V_S = \pm 2.3\text{V to } \pm 18\text{V}$	110	140		dB
		$G = 1000, V_S = \pm 2.3\text{V to } \pm 18\text{V}$	110	140		dB
Input Current						
I_B	Input Bias Current	$V_S = \pm 16.5\text{V}$	-2	0.5	2	nA
	Average Temperature Coefficient	$V_S = \pm 16.5\text{V}$		3		$\text{pA}/^\circ\text{C}$
I_{OS}	Input Offset Current	$V_S = \pm 16.5\text{V}$	-1		1	nA
Input						
	Input Impedance	Differential		10, 2		$\text{G}\Omega, \text{pF}$
		Common-Mode			10, 2	
IVR	Input Voltage Range ⁽²⁾	$V_S = \pm 4.5\text{V}, G = 1$	$-V_S + 1.9$		$+V_S - 1.2$	V
		$V_S = \pm 16.5\text{V}, G = 1$	$-V_S + 1.9$		$+V_S - 1.4$	V
CMRR	Common-Mode Rejection Ratio	$G = 1, V_S = \pm 16.5\text{V}$	70	90		dB
		$G = 10, V_S = \pm 16.5\text{V}$	90	110		dB
		$G = 100, V_S = \pm 16.5\text{V}$	108	130		dB
		$G = 1000, V_S = \pm 16.5\text{V}$	108	130		dB
Output						
V_{OUT}	Output Swing	$V_S = \pm 2.3\text{V to } \pm 4.5\text{V}$	$-V_S + 1.1$		$+V_S - 1.2$	V
		$V_S = \pm 18\text{V}, G = 1$	$-V_S + 1.4$		$+V_S - 1.2$	V
I_{SC}	Short Circuit Current			± 20		mA
Dynamic Performance						
BW_{-3dB}	Small Signal -3dB Bandwidth	$G = 1$		700		kHz
		$G = 10$		400		kHz
		$G = 100$		100		kHz
		$G = 1000$		12		kHz
SR	Slew Rate	$G = 10, V_S = \pm 15\text{V}$	0.6	1.2		$\text{V}/\mu\text{s}$
t_S	Settling Time to 0.01%	5V step, $G = 1$ to 100		13		μs
		5V step, $G = 1000$		110		μs

Electrical Characteristics continued

$T_A = 25^\circ\text{C}$, $V_S = \pm 15\text{V}$, $R_L = 2\text{k}\Omega$ to GND; unless otherwise noted. Gain = $1 + (49.4\text{k}/R_G)$; Total RTI Error = $V_{OS1} + (V_{OSO}/G)$

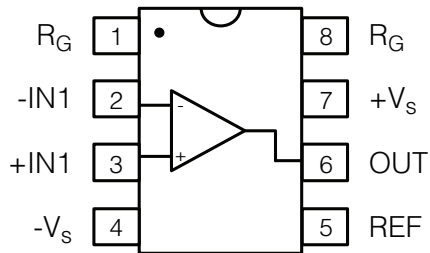
Symbol	Parameter	Conditions	Min	Typ	Max	Units
Noise						
e_{ni}	Input Voltage Noise	1kHz, $G = 1000$, $V_S = \pm 15\text{V}$		6.6	13	nV/ $\sqrt{\text{Hz}}$
e_{no}	Output Voltage Noise	1kHz, $G = 1$, $V_S = \pm 15\text{V}$		70	100	nV/ $\sqrt{\text{Hz}}$
e_{npp}	Peak-to-Peak Noise (RTI)	$G = 1$, 0.1Hz to 10Hz		5		μV_{pp}
		$G = 10$, 0.1Hz to 10Hz, $V_S = \pm 15\text{V}$			0.8	μV_{pp}
		$G = 100$, 0.1Hz to 10Hz, $V_S = \pm 15\text{V}$		0.2	0.4	μV_{pp}
i_n	Current Noise	$f = 1\text{kHz}$		100		fA/ $\sqrt{\text{Hz}}$
i_{npp}	Peak-to-Peak Current Noise	0.1Hz to 10Hz		10		pA $_{pp}$
Reference Input						
R_{IN}	Input Resistance			20		k Ω
I_{IN}	Input Current	$V_S = \pm 16.5\text{V}$		50	60	μA
	Voltage Range		$-V_S + 1.6$		$+V_S - 1.6$	V
	Gain to Output		1 \pm 0.0001			
Power Supply						
V_S	Operating Range		± 2.3		± 18	V
I_S	Supply Current	$V_S = \pm 16.5\text{V}$		1.3	2.2	mA

Notes:

- Nominal reference voltage gain is 1.0
- Input voltage range = $\text{CMV} + (G V_{DIFF})/2$

CLC1200 Pin Configurations

SOIC-8, DIP-8



CLC1200 Pin Assignments

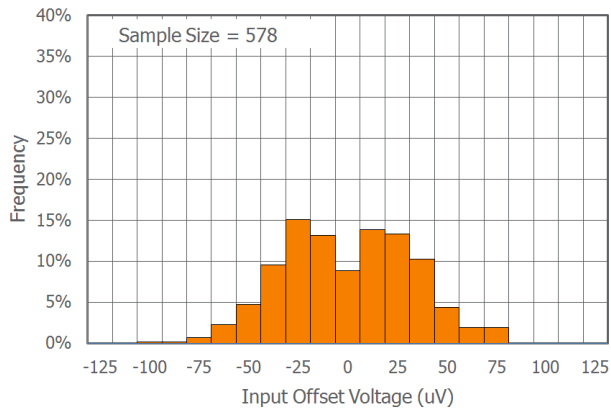
SOIC-8, DIP-8

Pin No.	Pin Name	Description
1, 8	R_G	R_G sets gain
2	-IN	Negative input
3	+IN	Positive input
4	$-V_S$	Negative supply
5	REF	Output is referred to the REF pin potential
6	OUT	Output
7	$+V_S$	Positive supply

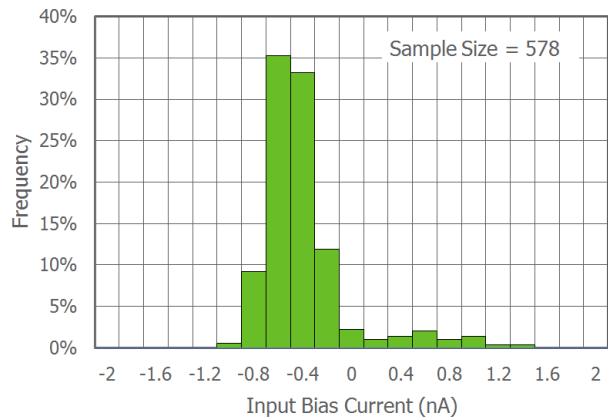
Typical Performance Characteristics

$T_A = 25^\circ\text{C}$, $V_S = \pm 15\text{V}$, $R_L = 2\text{k}\Omega$ to GND; unless otherwise noted.

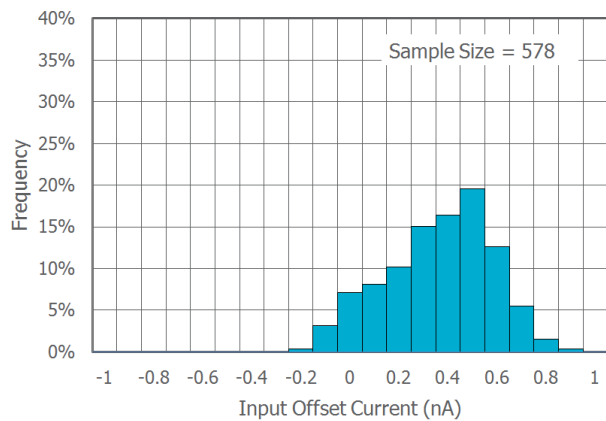
Input Offset Distribution (typical)



Input Bias Current Distribution (typical)



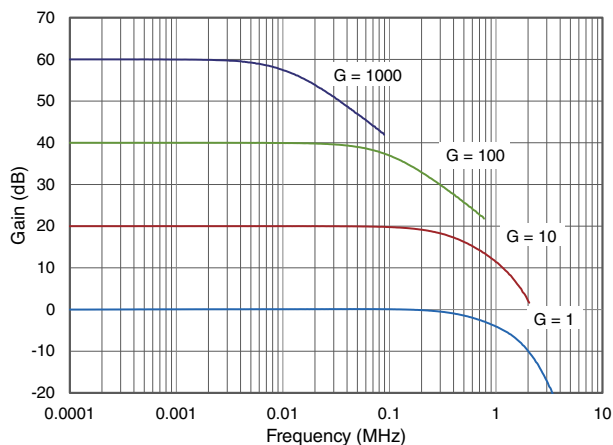
Input Offset Current Distribution (typical)



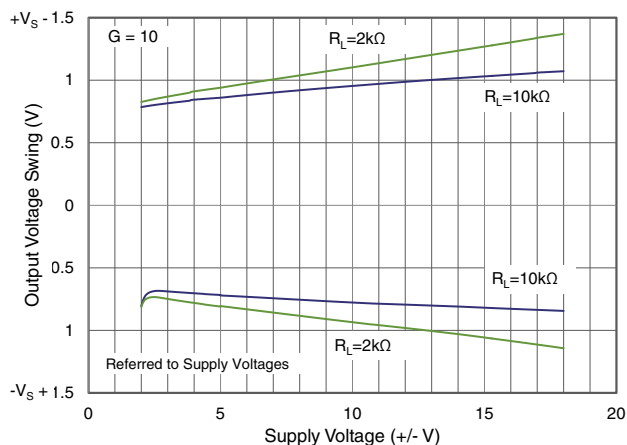
Typical Performance Characteristics

$T_A = 25^\circ\text{C}$, $V_S = \pm 15\text{V}$, $R_L = 2\text{k}\Omega$ to GND; unless otherwise noted.

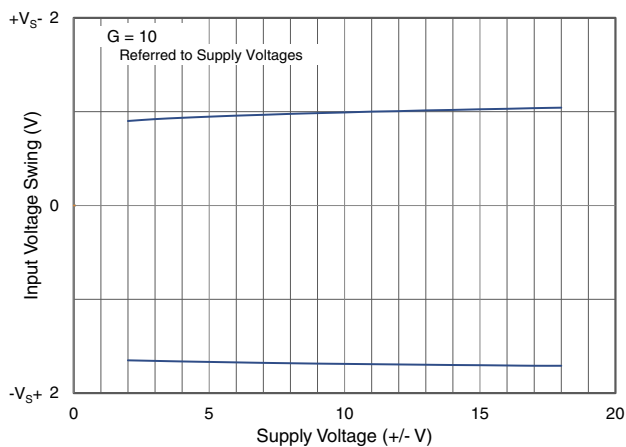
Gain vs. Frequency



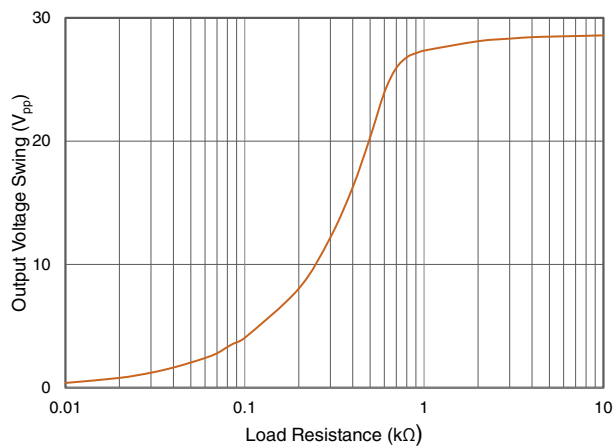
Output Voltage Swing vs. V_S



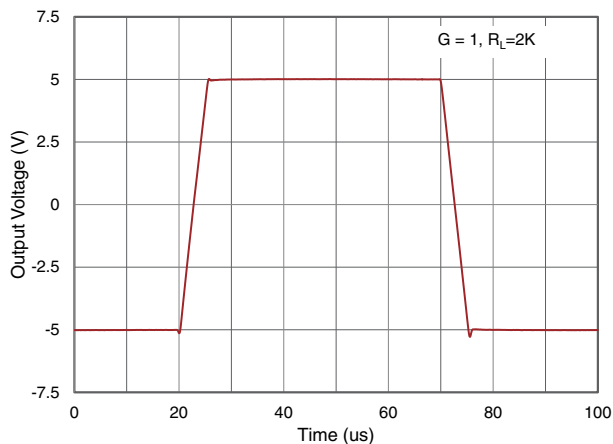
Input Voltage Range vs. V_S



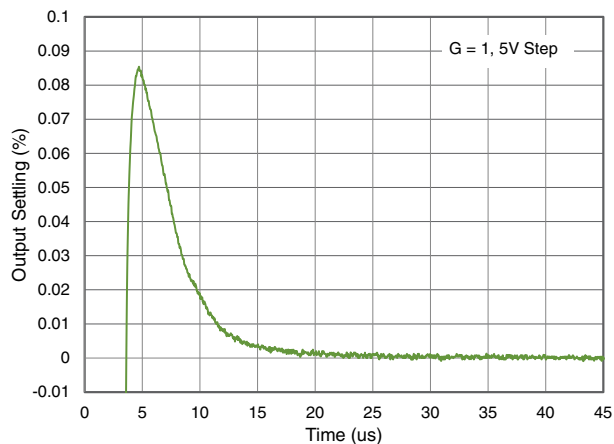
Output Voltage Swing vs. R_L



Large Signal Pulse Response ($G = 1$)



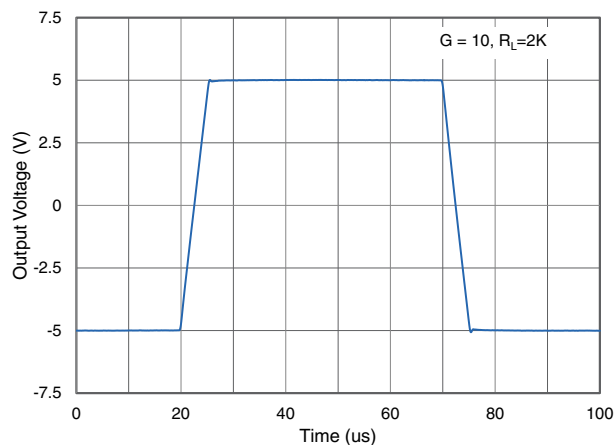
Large Signal Settling Time ($G = 1$)



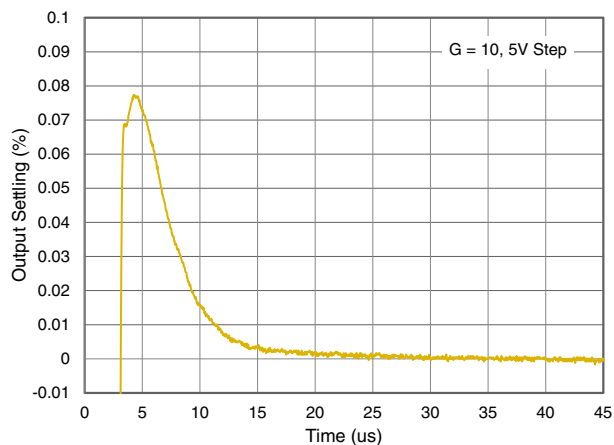
Typical Performance Characteristics

$T_A = 25^\circ\text{C}$, $V_S = \pm 15\text{V}$, $R_L = 2\text{k}\Omega$ to GND; unless otherwise noted.

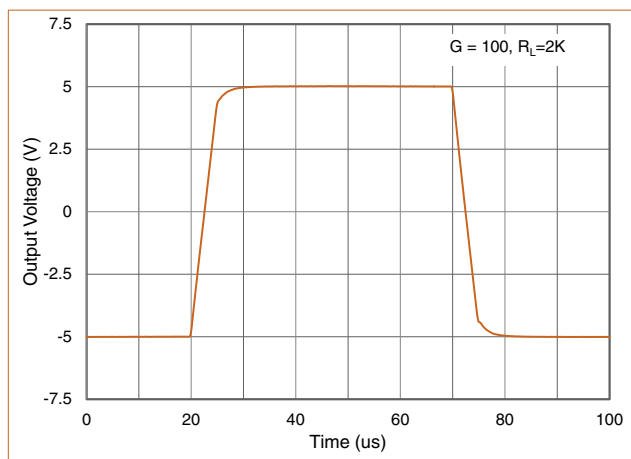
Large Signal Pulse Response ($G = 10$)



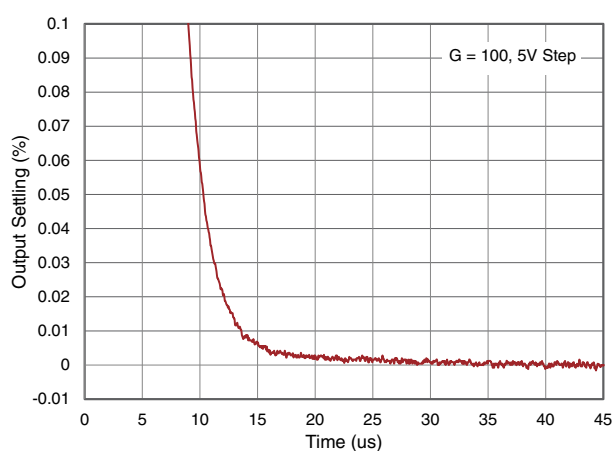
Large Signal Settling Time ($G = 10$)



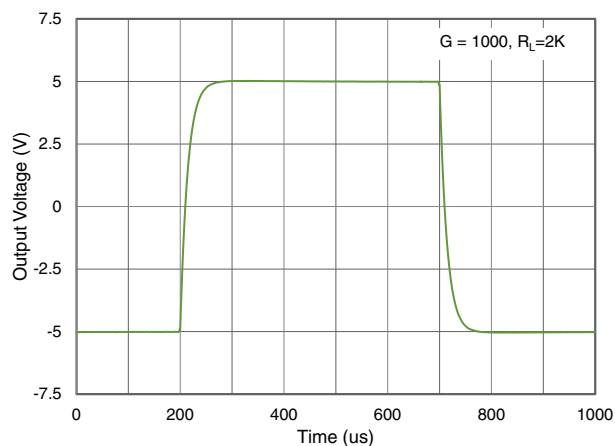
Large Signal Pulse Response ($G = 100$)



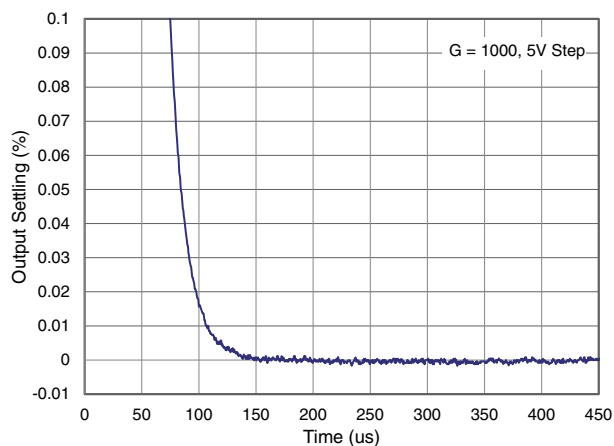
Large Signal Settling Time ($G = 100$)



Large Signal Pulse Response ($G = 1000$)



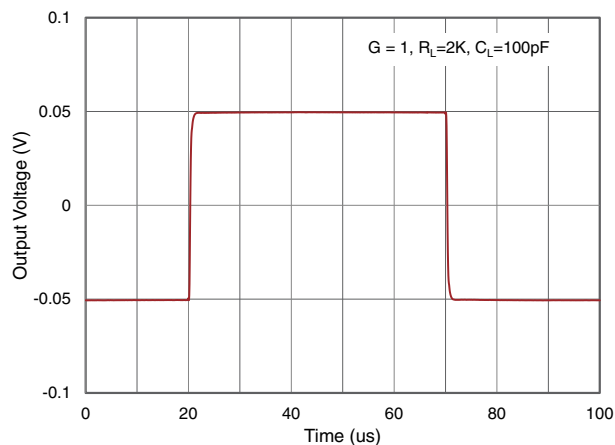
Large Signal Settling Time ($G = 1000$)



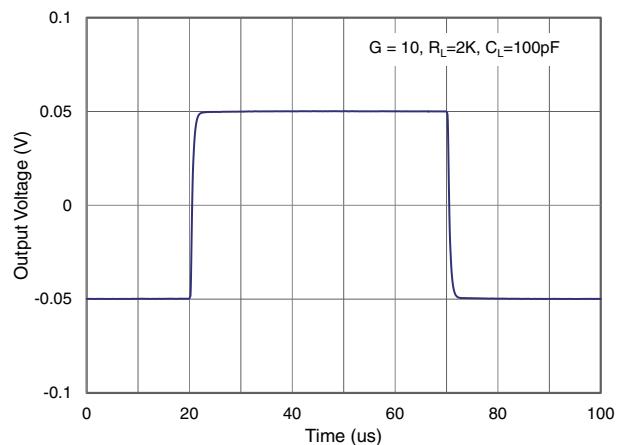
Typical Performance Characteristics

$T_A = 25^\circ\text{C}$, $V_S = \pm 15\text{V}$, $R_L = 2\text{k}\Omega$ to GND; unless otherwise noted.

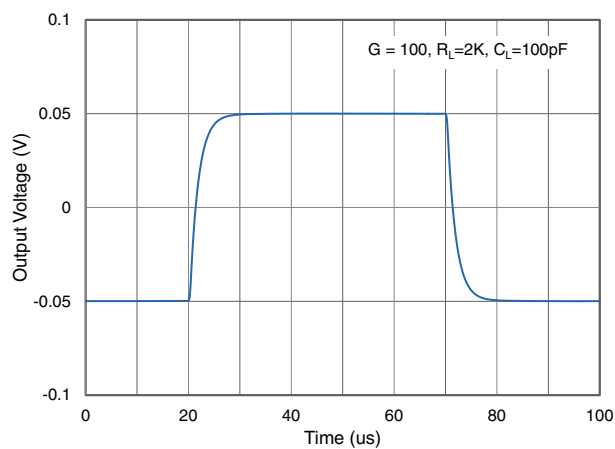
Small Signal Pulse Response ($G = 1$)



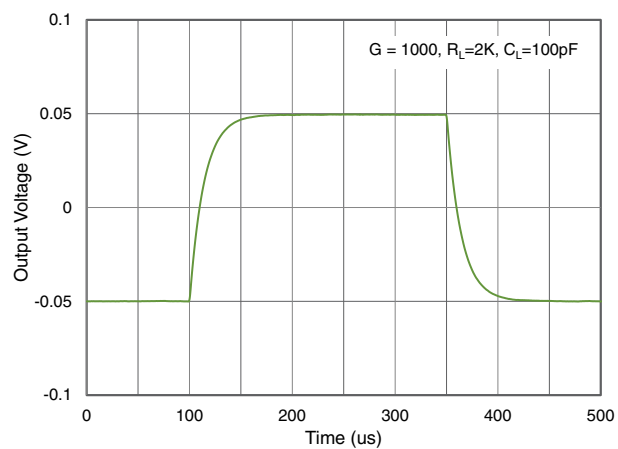
Small Signal Pulse Response ($G = 10$)



Small Signal Pulse Response ($G = 100$)



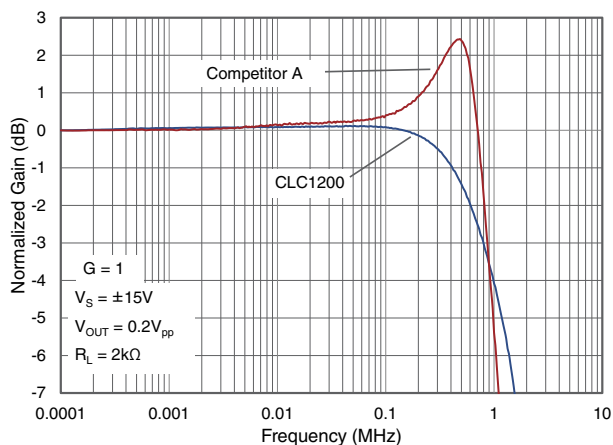
Small Signal Pulse Response ($G = 1000$)



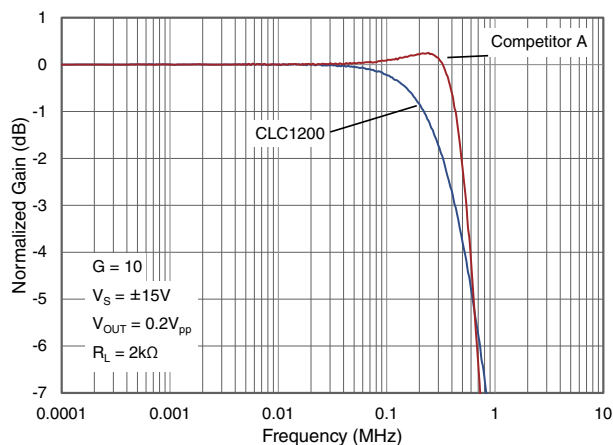
Typical Competitive Comparison Plots

$T_A = 25^\circ\text{C}$, $V_S = \pm 15\text{V}$, $R_L = 2\text{k}\Omega$, Resurgent evaluation board; unless otherwise noted.

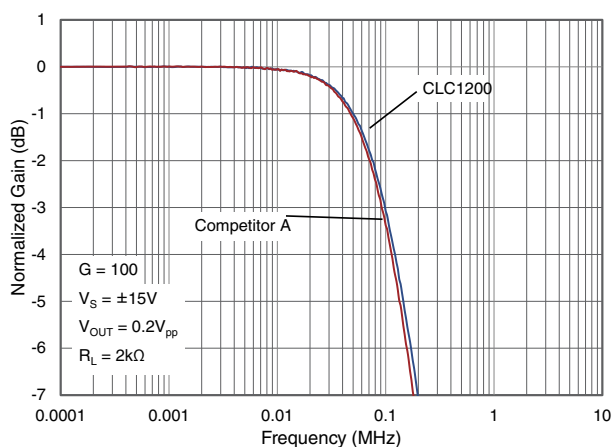
Frequency Response ($G = 1$)



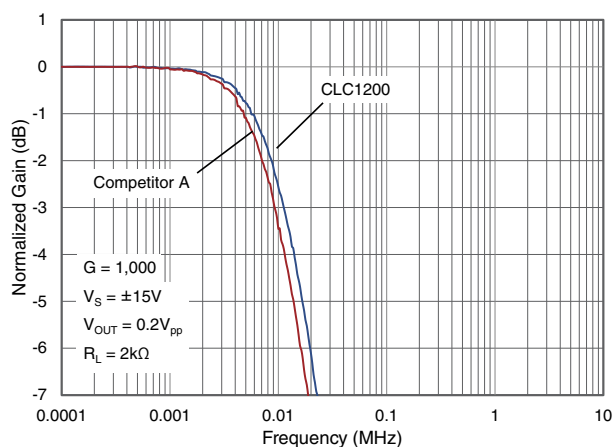
Frequency Response ($G = 10$)



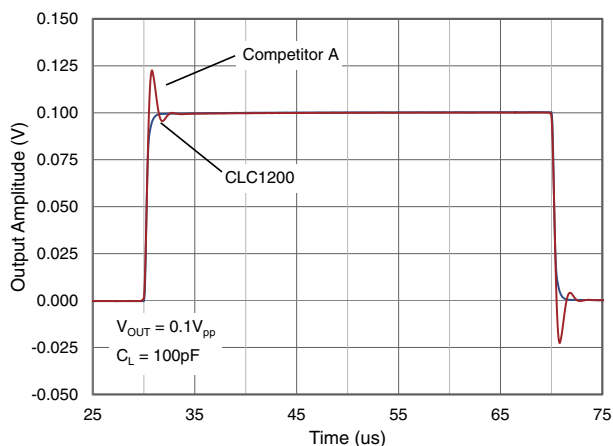
Frequency Response ($G = 100$)



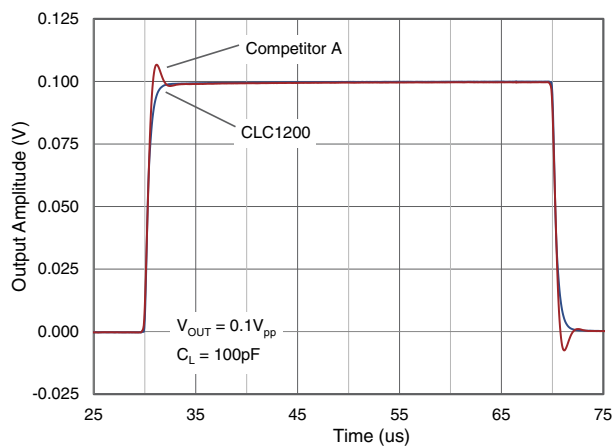
Frequency Response ($G = 1000$)



Small Signal Pulse Response ($G = 1$)



Small Signal Pulse Response ($G = 10$)



Application Information

Basic Information

The CLC1200 is a monolithic instrumentation amplifier based on the classic three op amp solution, refer to the Functional Block Diagram shown in Figure 1. The CLC1200 produces a single-ended output referred to the REF pin potential.

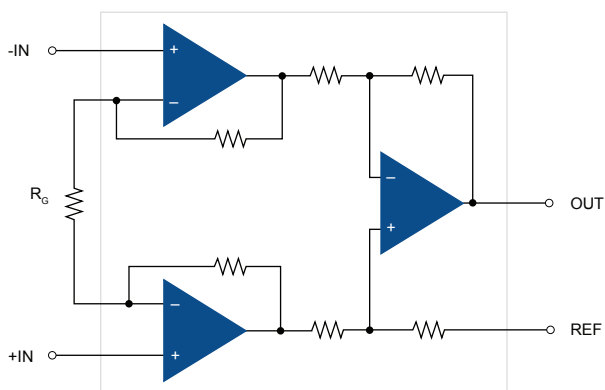


Figure 1: Functional Block Diagram

The internal resistors are trimmed which allows the gain to be accurately adjusted with one external resistor R_G .

$$G = \frac{49.4k}{R_G} + 1; R_G = \frac{49.4k}{G - 1}$$

R_G also determines the transconductance of the preamp stage. As R_G is reduced for larger gains, the transconductance increases to that of the input transistors. Producing the following advantages:

- Open-loop gain increases as the gain is increased, reducing gain related errors
- Gain-bandwidth increases as the gain is increased, optimizing frequency response
- Reduced input voltage noise which is determined by the collector current and base resistance of the input devices

Gain Selection

The impedance between pins 1 and 8, R_G , sets the gain of the CLC1200. Table 1 shows the required standard table values of R_G for various calculated gains. For $G = 1$, $R_G = \infty$.

1% R_G (Ω)	Calculated Gain	0.1% R_G (Ω)	Calculated Gain
49.9k	1.990	49.3k	2.002
12.4k	4.984	12.4k	4.984
5.49k	9.998	5.49k	9.998
2.61k	19.93	2.61k	19.93
1.00k	50.40	1.01k	49.91
499	100.0	499	100.0
249	199.4	249	199.4
100	495.0	98.8	501.0
49.9	991.0	49.3	1,003.0

Table 1: Recommended R_G Values

Follow these guidelines for improved performance:

- To maintain gain accuracy, use 0.1% to 1% resistors
- To minimize gain error, avoid high parasitic resistance in series with R_G
- To minimize gain drift, use low TC resistors (<10ppm/°C)

Common Mode Rejection

The CLC1200 offers high CMRR. To achieve optimal CMRR performance:

- Connect the reference terminal (pin 5) to a low impedance source
- Minimize capacitive and resistive differences between the inputs

In many applications, shielded cables are used to minimize noise. Properly drive the shield for best CMRR performance over frequency. Figures 1 and 2 show active data guards that are configured to improve AC common-mode rejections. the capacitances of input cable shields are “bootstrapped” to minimize the capacitance mismatch between the inputs.

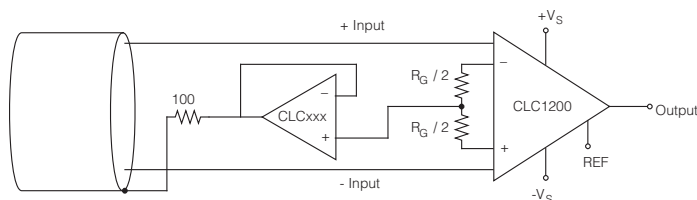


Figure 2: Common-mode Shield Driver

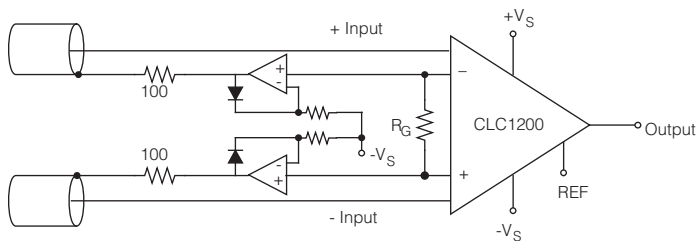


Figure 3: Differential Shield Driver

Pressure Measurement Applications

The CLC1200 is especially suitable for higher resistance pressure sensors powered at lower voltages where small size and low power become more significant.

Figure 3 shows a 3kΩ pressure transducer bridge powered from 5V. In such a circuit, the bridge consumes only 1.7mA. Adding the CLC1200 and a buffered voltage divider allows the signal to be conditioned for only 3.8mA of total supply current.

Small size and low cost make the CLC1200 especially attractive for voltage output pressure transducers. Since it delivers low noise and drift, it will also serve applications such as diagnostic noninvasive blood pressure measurement.

Medical ECG

The CLC1200 is perfect for ECG monitors because of its low current noise. A typical application is shown in Figure 4. The CLC1200's low power, low supply voltage requirements, and space-saving 8-lead SOIC package offerings make it an excellent choice for battery-powered data recorders.

Furthermore, the low bias currents and low current noise, coupled with the low voltage noise of the CLC1200, improve the dynamic range for better performance.

The value of capacitor C1 is chosen to maintain stability of the right leg drive loop. Proper safeguards, such as isolation, must be added to this circuit to protect the patient from possible harm.

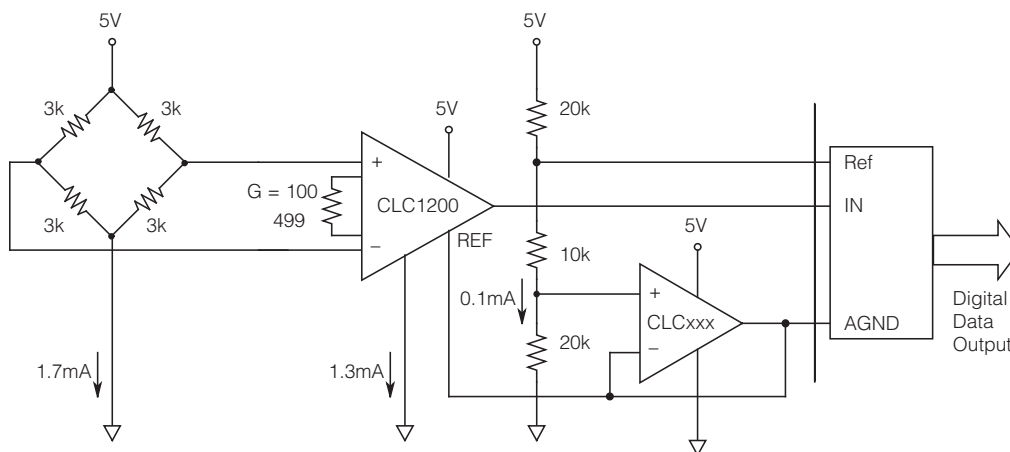


Figure 4: Pressure Monitoring Circuits Operating on a Single 5V Supply

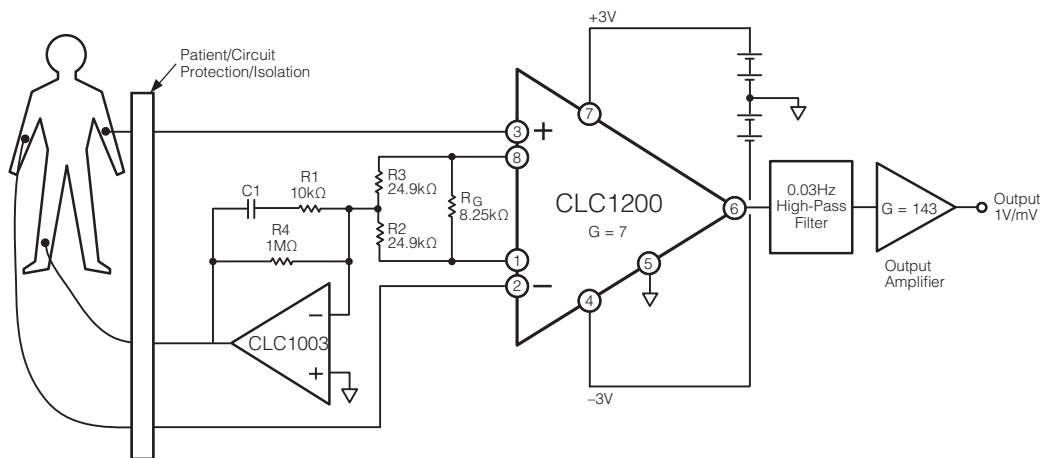


Figure 5: Typical Circuit for ECG Monitor Applications

Grounding

The output voltage of the CLC1200 is developed with respect to the potential on the reference terminal (pin 8). Simply tie the REF pin to the appropriate “local ground” to resolve many grounding problems.

To isolate low level analog signals from a noisy digital environment, many data acquisition components have separate analog and digital ground pins. Use separate ground lines (analog and digital) to minimize current flow from sensitive areas to system ground. These ground returns must be tied together at some point, usually best at the ADC.

Layout Considerations

General layout and supply bypassing play major roles in high frequency performance. Resurgent has evaluation boards to use as a guide for high frequency layout and as an aid in device testing and characterization. Follow the steps below as a basis for high frequency layout:

- Include 6.8 μ F and 0.1 μ F ceramic capacitors for power supply decoupling
- Place the 6.8 μ F capacitor within 0.75 inches of the power pin
- Place the 0.1 μ F capacitor within 0.1 inches of the power pin
- Remove the ground plane under and around the part, especially near the input and output pins to reduce parasitic capacitance
- Minimize all trace lengths to reduce series inductances

Refer to the evaluation board layouts below for more information.

Evaluation Board Information

The following evaluation boards are available to aid in the testing and layout of these devices:

Evaluation Board #	Products
CEB024	CLC1200 in SOIC-8

Evaluation Board Schematics

Evaluation board schematics and layouts are shown in Figures 6-8. These evaluation boards are built for dual-supply operation. Follow these steps to use the board in a single-supply application:

1. Short $-V_S$ to ground.
2. Use C3 and C4, if the $-V_S$ pin of the amplifier is not directly connected to the ground plane.

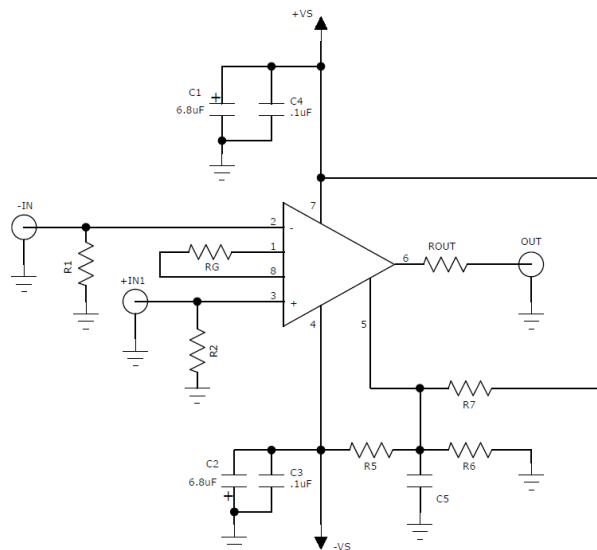


Figure 6. CEB024 Schematic

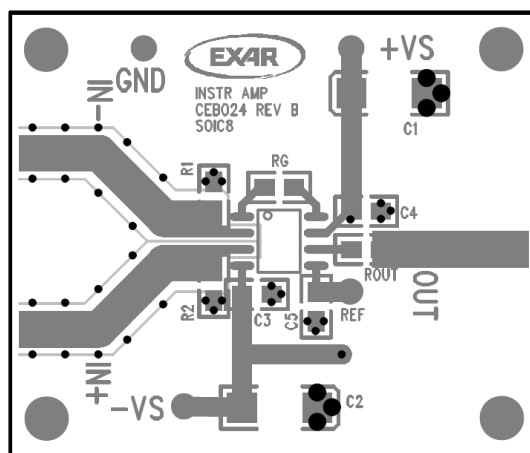


Figure 7. CEB024 Top View

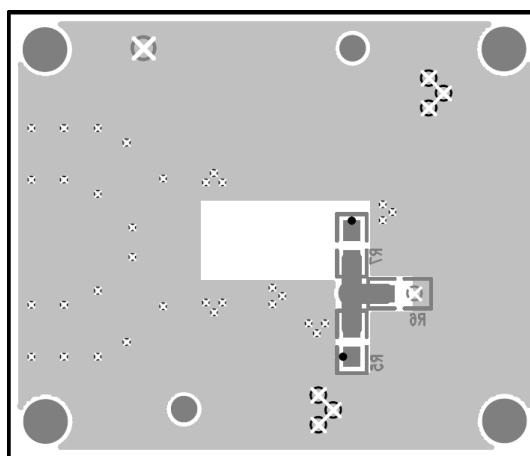
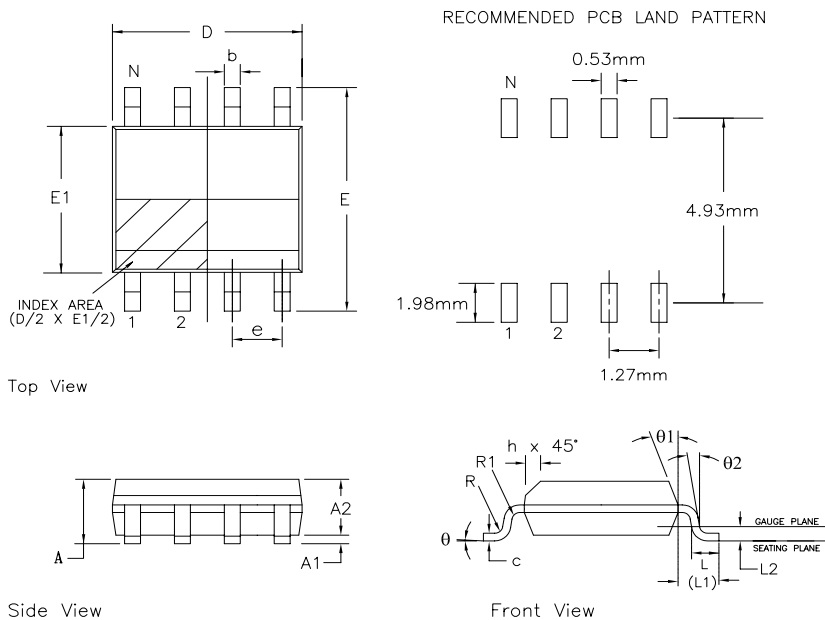


Figure 8. CEB024 Bottom View

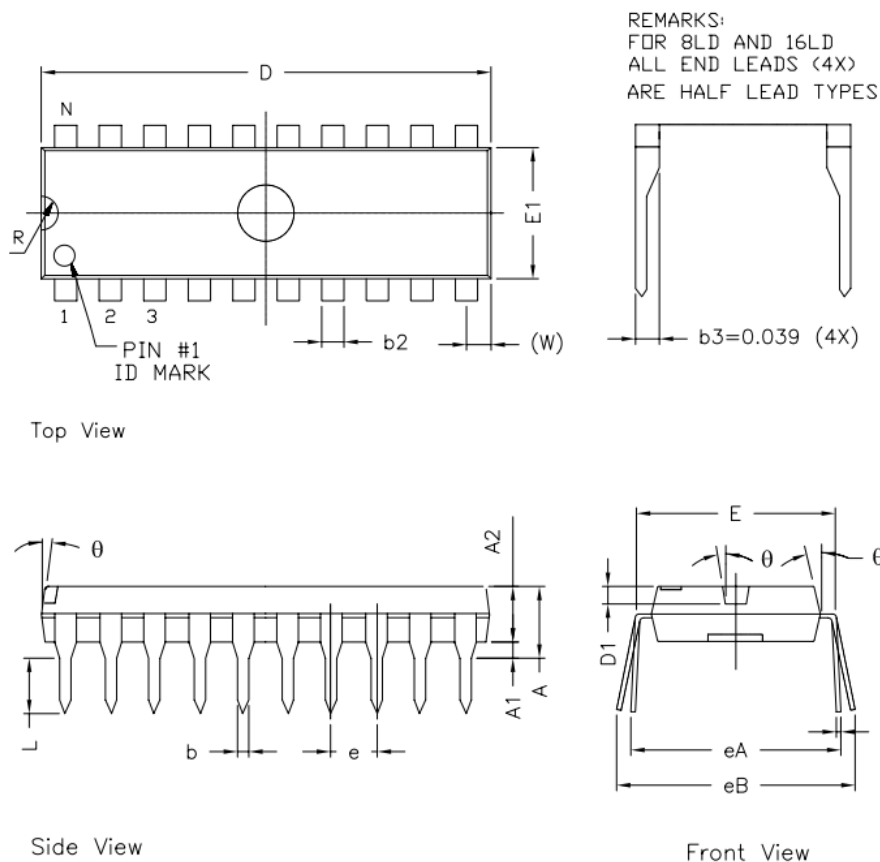
Mechanical Dimensions

SOIC-8 Package



8 Pin SOICN JEDEC MS-012 Variation AA						
SYMBOLS	DIMENSIONS IN MM (Control Unit)			DIMENSIONS IN INCH (Reference Unit)		
	MIN	NOM	MAX	MIN	NOM	MAX
A	1.35	—	1.75	0.053	—	0.069
A1	0.10	—	0.25	0.004	—	0.010
A2	1.25	—	1.65	0.049	—	0.065
b	0.31	—	0.51	0.012	—	0.020
c	0.17	—	0.25	0.007	—	0.010
E	6.00 BSC			0.236 BSC		
E1	3.90 BSC			0.154 BSC		
e	1.27 BSC			0.050 BSC		
h	0.25	—	0.50	0.010	—	0.020
L	0.40	—	1.27	0.016	—	0.050
L1	1.04 REF			0.041 REF		
L2	0.25 BSC			0.010 BSC		
R	0.07	—	—	0.003	—	—
R1	0.07	—	—	0.003	—	—
θ	0°	—	8°	0°	—	8°
θ1	5°	—	15°	5°	—	15°
θ2	0°	—	—	0°	—	—
D	4.90 BSC			0.193 BSC		
N	8			8		

DIP-8 Package



8 Pin PDIP JEDEC MS-001 Variation BA						
SYMBOLS	DIMENSIONS IN INCH (Control Unit)			DIMENSIONS IN MM (Reference Unit)		
	MIN	NOM	MAX	MIN	NOM	MAX
A	—	—	0.210	—	—	5.33
A1	0.015	—	—	0.38	—	—
A2	0.115	0.130	0.195	2.92	3.30	4.95
b	0.014	0.018	0.022	0.36	0.46	0.56
b2	0.045	0.060	0.070	1.14	1.52	1.78
c	0.008	0.010	0.014	0.20	0.25	0.36
D1	0.030	—	0.060	0.76	—	1.52
E	0.300	0.310	0.325	7.62	7.87	8.26
E1	0.240	0.250	0.280	6.10	6.35	7.11
e	0.100 BSC			2.54 BSC		
eA	0.300 BSC			7.62 BSC		
eB	—	—	0.430	—	—	10.92
L	0.115	0.130	0.150	2.92	3.30	3.81
W	0.075 REF			1.91 REF		
R	0.030 BSC			0.76 BSC		
θ	4°	7°	10°	4°	7°	10°
D	0.355	0.365	0.400	9.02	9.27	10.16
N	8			8		

Ordering Information

Part Number	Package	Green	Operating Temperature Range	Packaging
CLC1200ISO8X	SOIC-8	Yes	-40°C to +85°C	Tape & Reel
CLC1200ISO8MTR	SOIC-8	Yes	-40°C to +85°C	Mini Tape & Reel
CLC1200ISO8EVB	Evaluation Board	N/A	N/A	N/A
CLC1200IDP8	DIP-8	Yes	-40°C to +85°C	Rail
CLC1200ICF	Die	Yes	-40°C to +85°C	Wafer

Moisture sensitivity level for all parts is MSL-1. Mini Tape and Reel contains 250 pieces.

Revision History

Revision	Date	Description
2E (ECN 1513-02)	March 2015	Reformat into Exar data sheet template. Updated PODs and thermal resistance numbers. Updated ordering information table to include MTR and EVB part numbers. Updated evaluation board top and bottom views to Rev b. Added schematic used for evaluation boards.
2E.R	July 2018	Updated to Resurgent Semiconductor.

For Further Assistance:

www.resurgentsemi.net



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